

MDA100G THRU MDA110G

# SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER

## VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

#### **FEATURES**

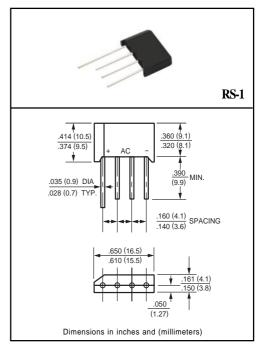
- \* Low cost
- \* Low leakage
- \* Low forward voltage \* Mounting position: Any
- \* Weight: 1.26 grams

#### **MECHANICAL DATA**

- \* UL listed the recognized component directory, file #E94233
- \* Epoxy: Device has UL flammability classification 94V-O

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



### MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	MDA100G	MDA101G	MDA102G	MDA104G	MDA106G	MDA108G	MDA110G	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at TA = 75°C	lo	1.0						Amps	
Peak Forward Surge Current 8.3 ms single half sine-wave	IFSM 30						Amps		
superimposed on rated load (JEDEC method)	IFSM	30							
Typical Thermal Resistance from junction to case	RθJC	15						°C/W	
Typical Thermal Resistance from junction to ambient	RθJA	50							
Operating Temperature Range	TJ	-55 to + 150						٥C	
Storage Temperature Range	Тѕтс	-55 to + 150							٥C

#### ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS		SYMBOL	MDA100G MDA101G MDA102G MDA104G MDA106G MDA108G MDA110G	UNITS
Maximum Forward Voltage Drop per Bridge Element at 1.57A DC		VF	1.3	Volts
Maximum Reverse Current at Rated	@Ta = 25°C	lr	5.0	uAmps
DC Blocking Voltage per element	@Ta = 100°C		1	mAmps

Note: "Fully ROHS compliant", "100% Sn plating(Pb-free).

## RATING AND CHARACTERISTIC CURVES (MDA100G THRU MDA110G)

